



# QPA2935

## 2 Watt S-Band GaN Driver Amplifier

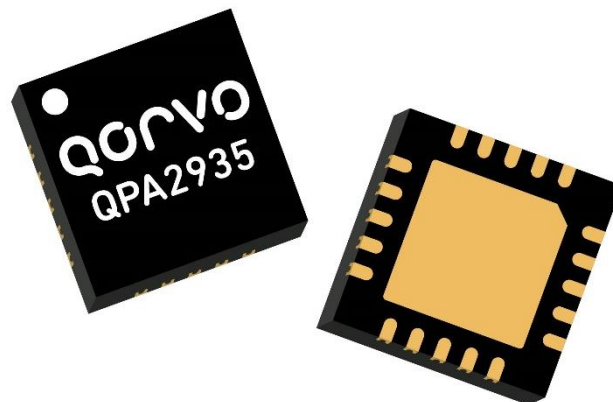
### Product Overview

Qorvo's QPA2935 is a MMIC power amplifier fabricated using Qorvo's QGaN25 0.25  $\mu\text{m}$  GaN on SiC production process. Covering 2.7–3.5 GHz, the QPA2935 typically provides 33 dBm of saturated output power and 18 dB of large-signal gain while achieving greater than 52 % power-added efficiency.

The QPA2935 can support a variety of operating conditions to best support system requirements. With good thermal properties, it can support a range of bias voltages. The QPA2935 is matched to 50 ohms with integrated DC blocking caps on both I/O ports..

The QPA2935 is packaged in a plastic overmolded 4x4 mm package. The QPA2935 is 100% DC and RF tested to ensure compliance to electrical specifications.

Lead free and RoHS compliant.

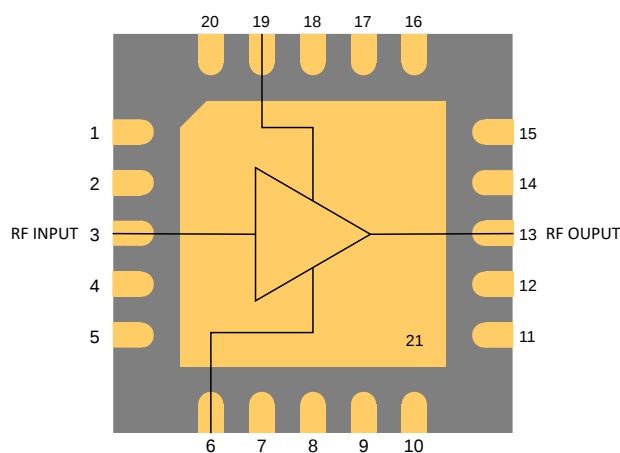


### Key Features

- Frequency Range: 2.7 – 3.5 GHz
- $P_{\text{SAT}}$  : 33 dBm ( $P_{\text{IN}} = 15$  dBm)
- PAE: > 52 % ( $P_{\text{IN}} = 15$  dBm)
- Small Signal Gain: 28.4 dB
- Bias:  $V_D = 25$  V,  $I_{DQ} = 29$  mA
- Package Dimensions: 4.00 x 4.00 x 0.85 mm

*Performance is typical across frequency. Please reference electrical specification table and data plots for more details.*

### Functional Block Diagram



Top View

### Applications

- Electronic Warfare
- Civilian and Military Radar

### Ordering Information

| Part No.   | Description                        |
|------------|------------------------------------|
| QPA2935    | 2 Watt S-Band GaN Driver Amplifier |
| QPA2935EVB | Evaluation Board for QPA2935       |
| QPA2935TR7 | 500 pcs. on 7 inch reel            |

## Absolute Maximum Ratings

| Parameter                                                                             | Value / Range    |
|---------------------------------------------------------------------------------------|------------------|
| Drain Voltage ( $V_D$ )                                                               | 40 V             |
| Gate Voltage Range ( $V_G$ )                                                          | -4 V to +1 V     |
| Drain Current ( $I_D$ )                                                               | 385 mA           |
| Gate Current ( $I_G$ )                                                                | See plot page 17 |
| $P_{DISS}$ (under drive), 85 °C                                                       | 11.5 W           |
| Input Power, $Z_L=50\ \Omega$ , $V_D=25\text{ V}$ , $I_{DQ}=29\text{ mA}$ , CW, 85 °C | 21 dBm           |
| Input Power, Output VSWR=3:1, $V_D=25\text{ V}$ , $I_{DQ}=29\text{ mA}$ , CW, 85 °C   | 21 dBm           |
| Soldering Temperature                                                                 | 260 °C           |
| Storage Temperature                                                                   | -55 to +125 °C   |

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

## Recommended Operating Conditions

| Parameter                  | Min | Typ | Max | Unit |
|----------------------------|-----|-----|-----|------|
| Drain Voltage ( $V_D$ )    |     | 25  |     | V    |
| Drain Current ( $I_{DQ}$ ) |     | 29  |     | mA   |
| Operating Temperature      | -40 | 25  | 85  | °C   |

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

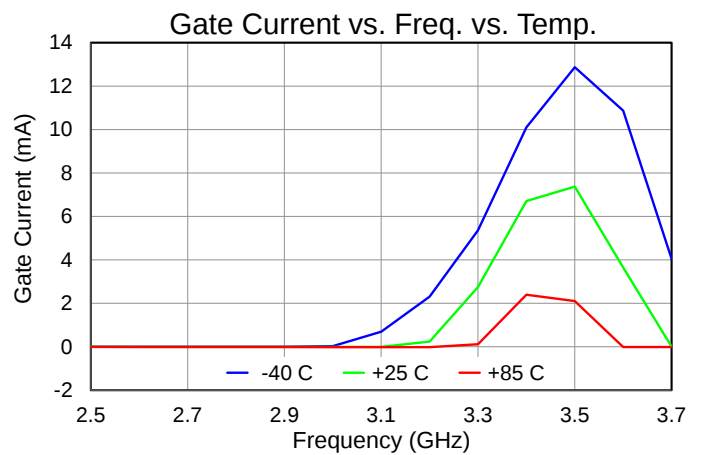
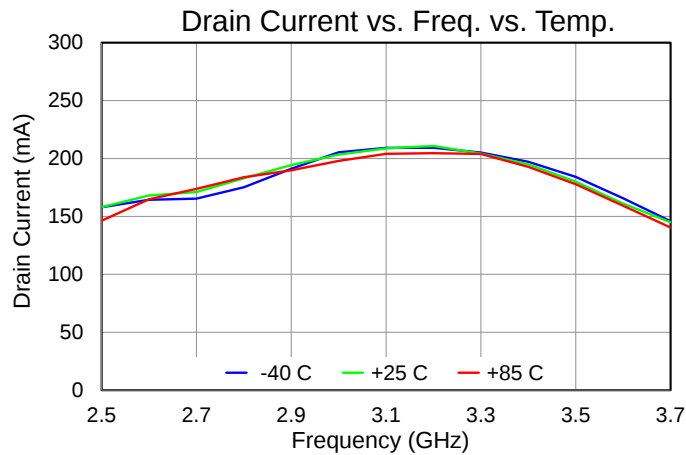
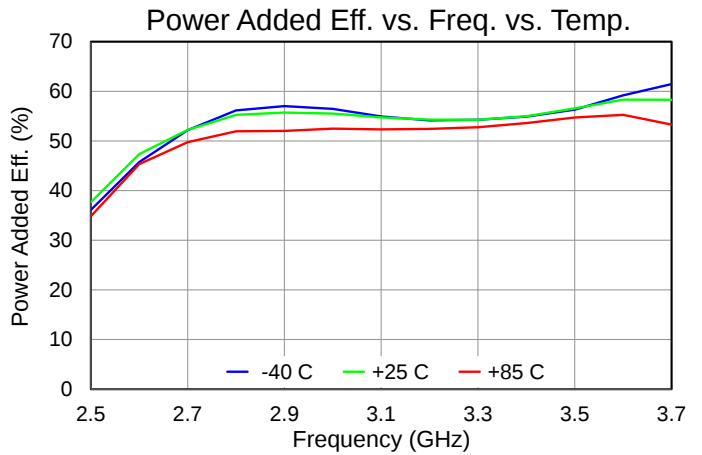
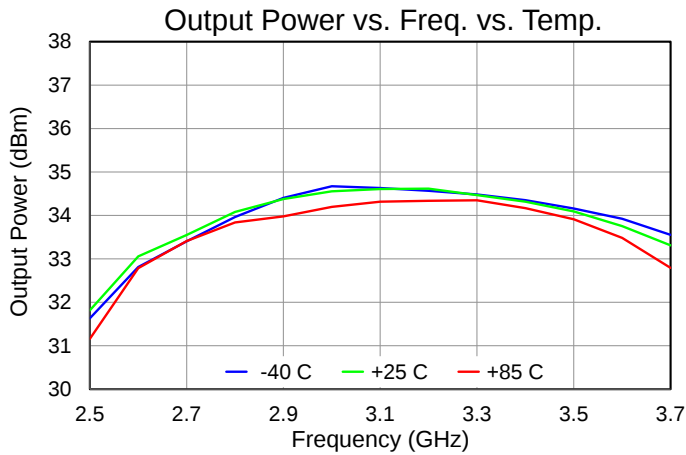
## Electrical Specifications

| Parameter                                                             | Min  | Typ    | Max | Units |
|-----------------------------------------------------------------------|------|--------|-----|-------|
| Operational Frequency                                                 | 2.7  |        | 3.5 | GHz   |
| Output Power ( $P_{IN}=15\text{ dBm}$ )                               |      | 34.3   |     | dBm   |
| Power Added Eff. ( $P_{IN}=15\text{ dBm}$ )                           |      | 54.8   |     | %     |
| Small Signal Gain                                                     |      | 28.4   |     | dB    |
| Input Return Loss                                                     |      | 15     |     | dB    |
| Output Return Loss                                                    |      | 7      |     | dB    |
| Second Harmonic Level ( $P_{IN}=15\text{ dBm}$ , 3.1 GHz)             |      | -27    |     | dBc   |
| Third Harmonic Level ( $P_{IN}=15\text{ dBm}$ , 3.1 GHz)              |      | -43    |     | dBc   |
| $P_{OUT}$ Temp. Coeff. (85 °C to -40 °C, $P_{IN} = 15\text{ dBm}$ )   |      | -0.002 |     | dB/°C |
| Sm. Sig. Gain Temp. Coefficient (85 °C to -40 °C)                     |      | -0.041 |     | dB/°C |
| Gate Leakage Current ( $V_D = +10\text{ V}$ , $V_G = -3.7\text{ V}$ ) | -1.3 |        |     | mA    |

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25\text{ °C}$ , CW

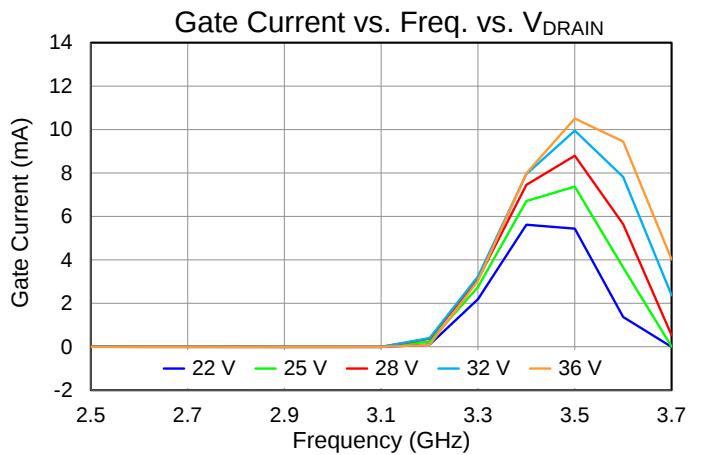
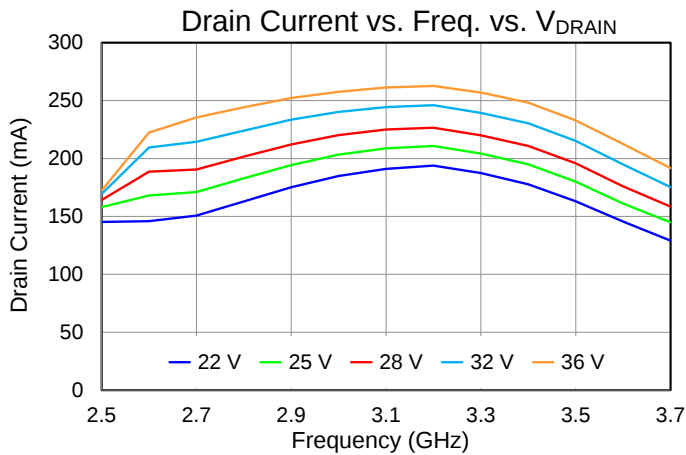
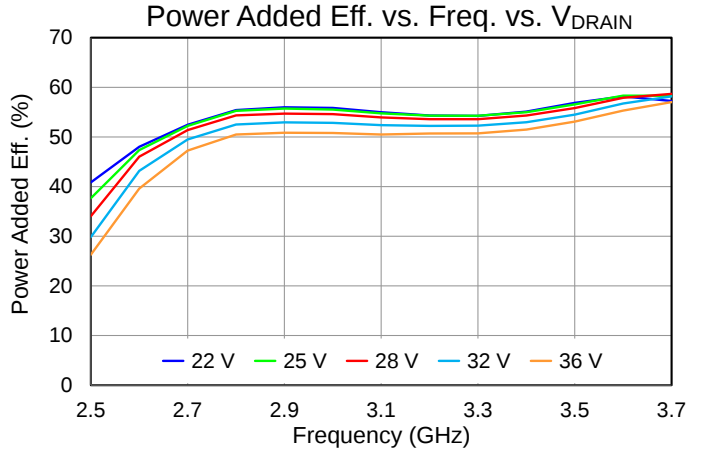
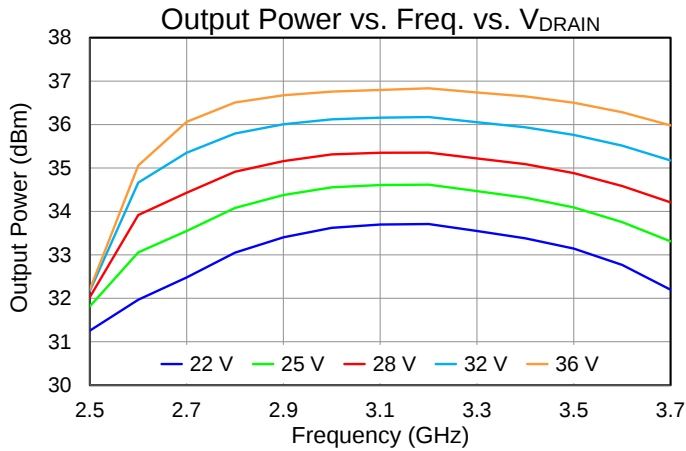
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



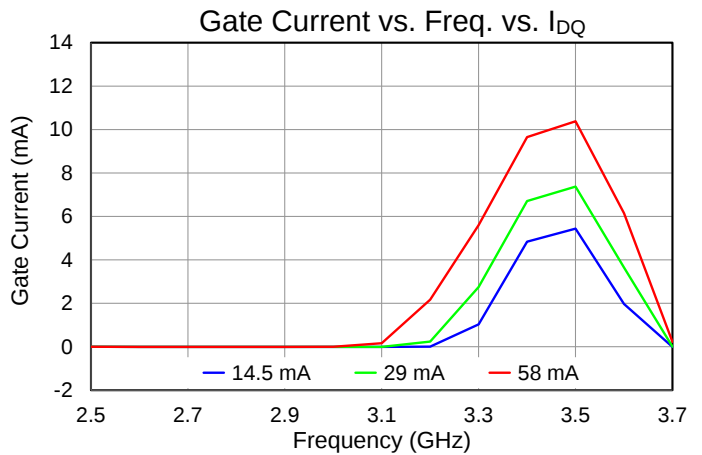
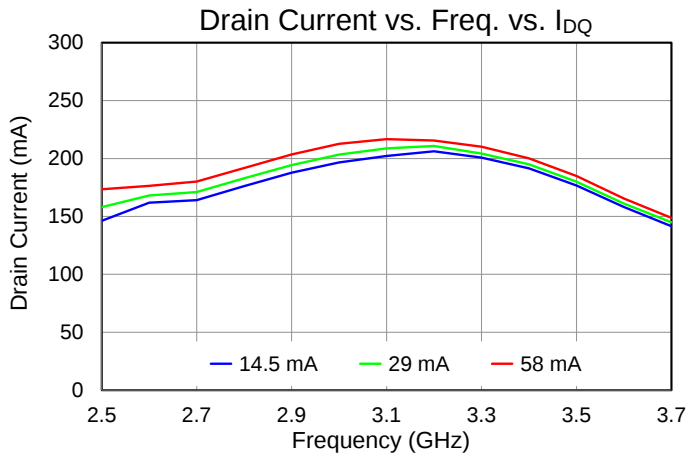
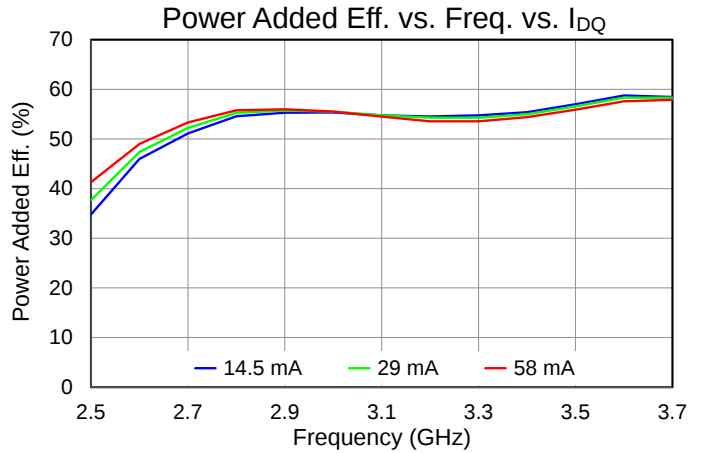
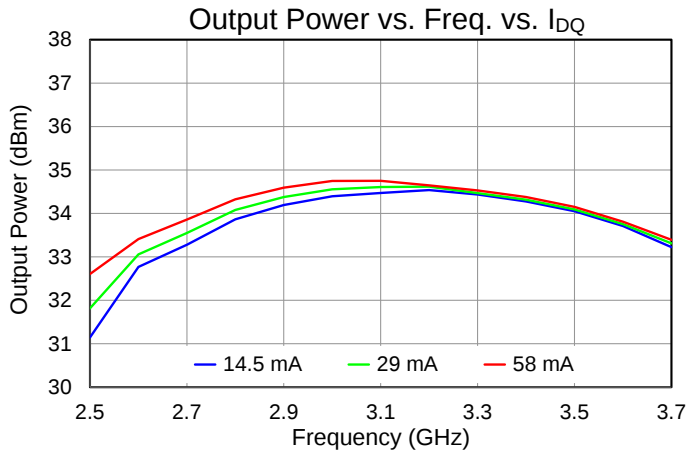
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



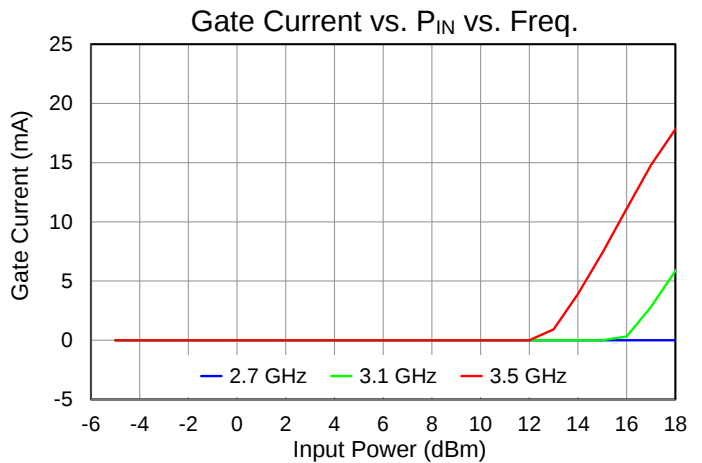
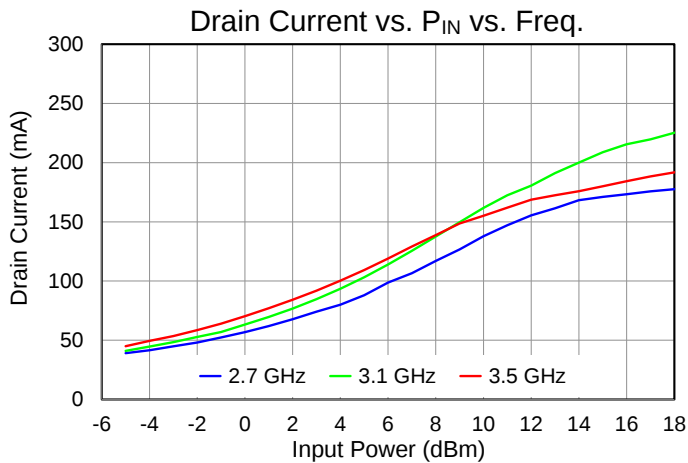
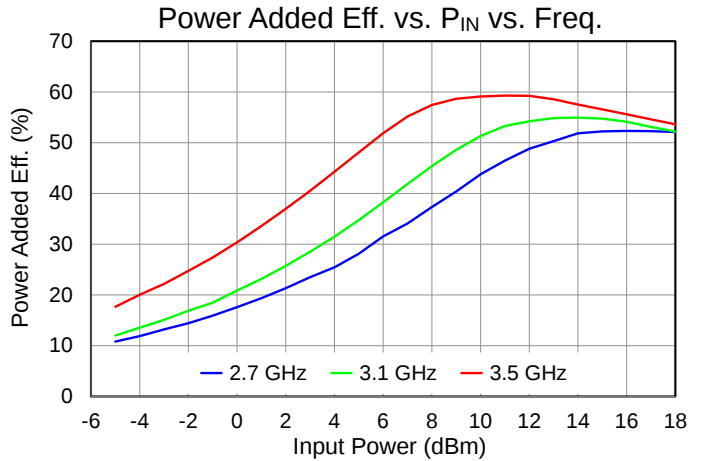
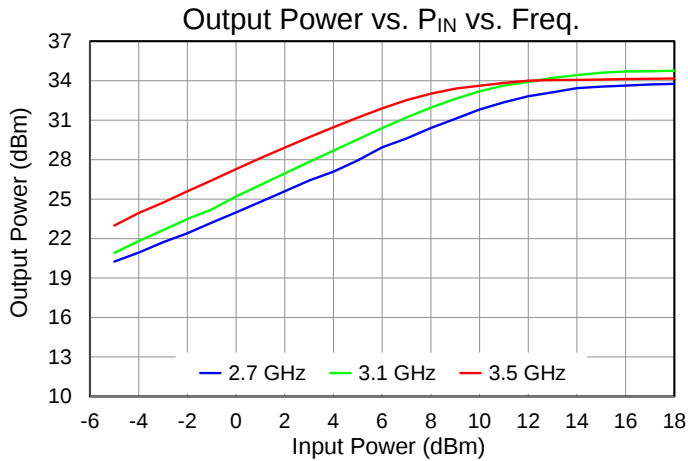
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



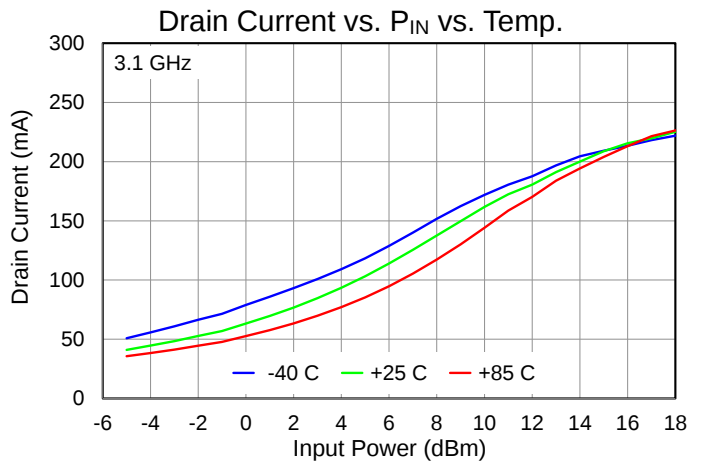
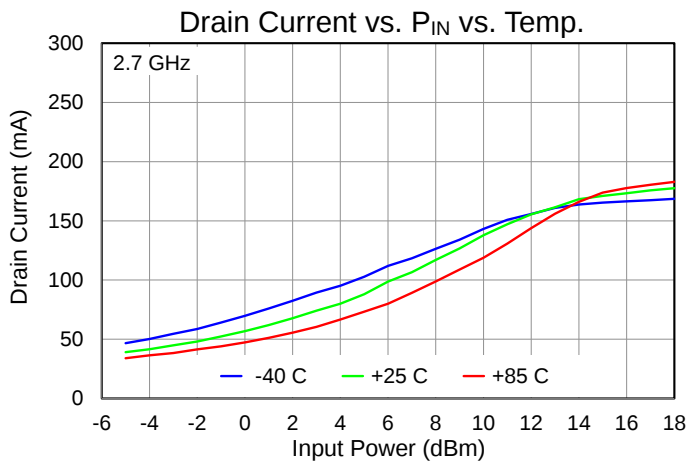
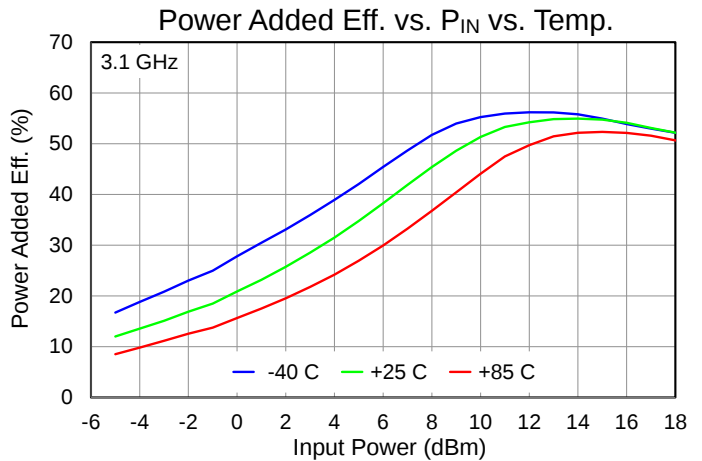
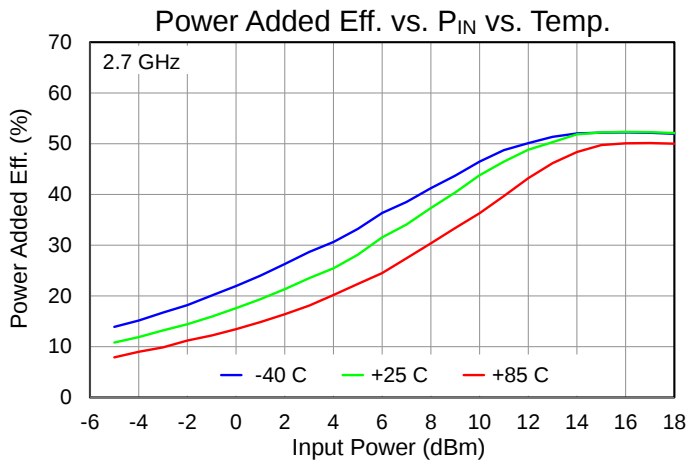
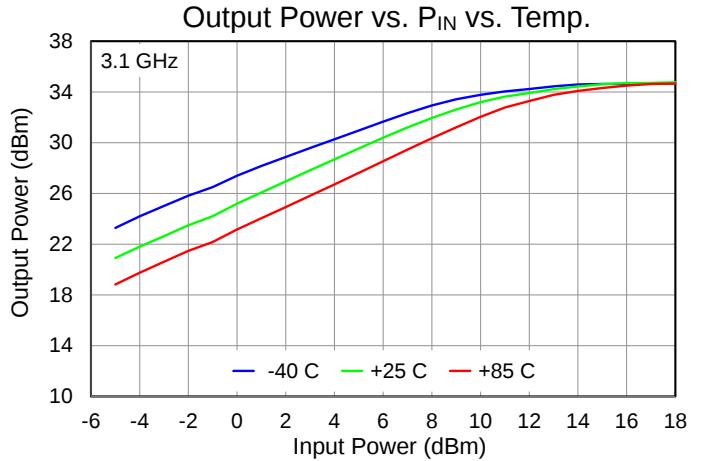
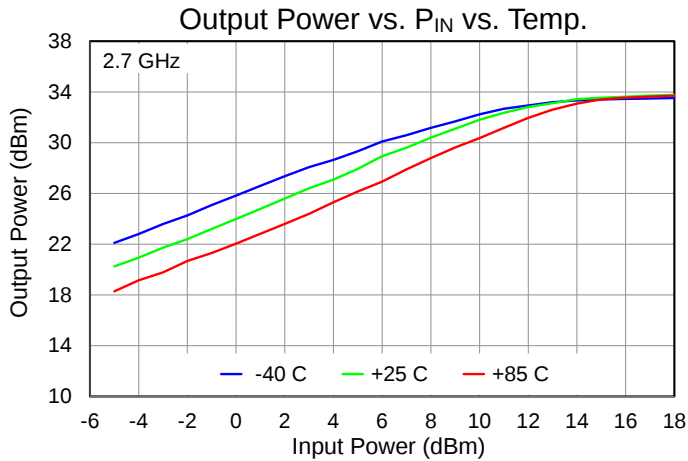
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25\text{ }^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



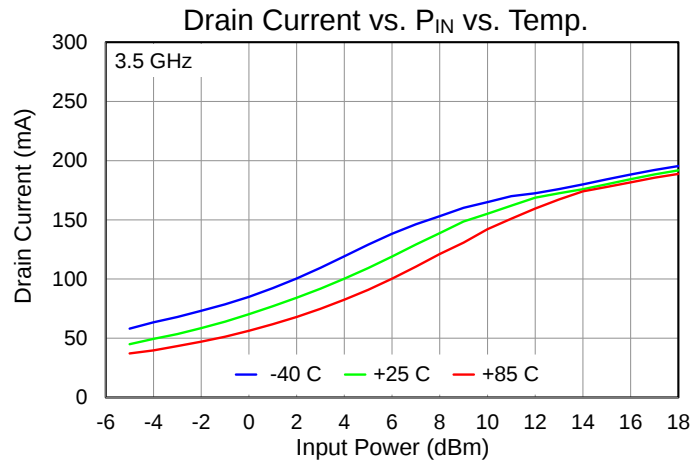
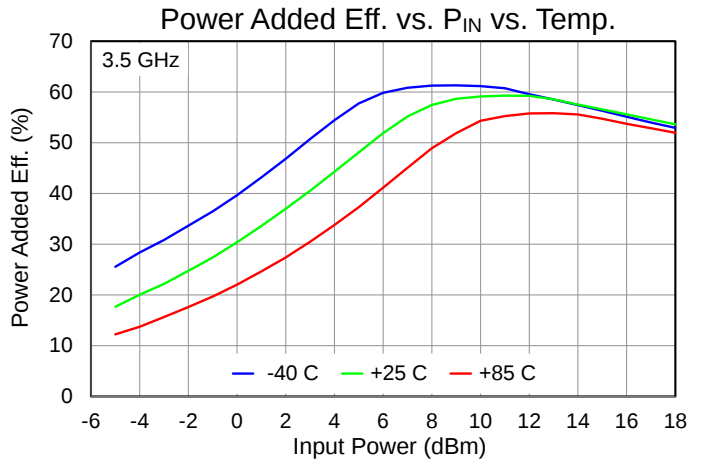
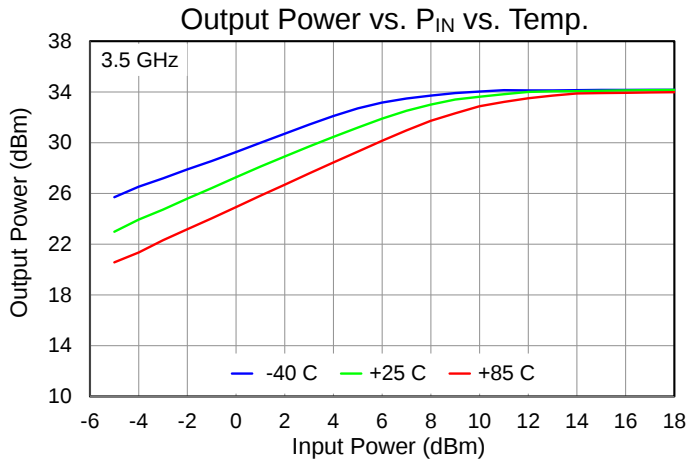
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



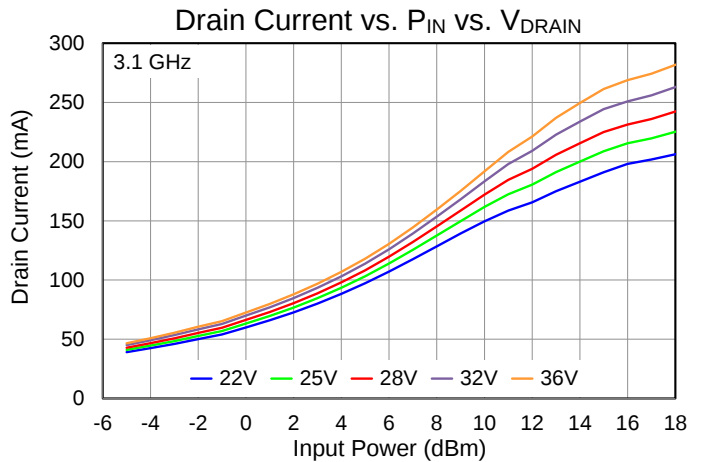
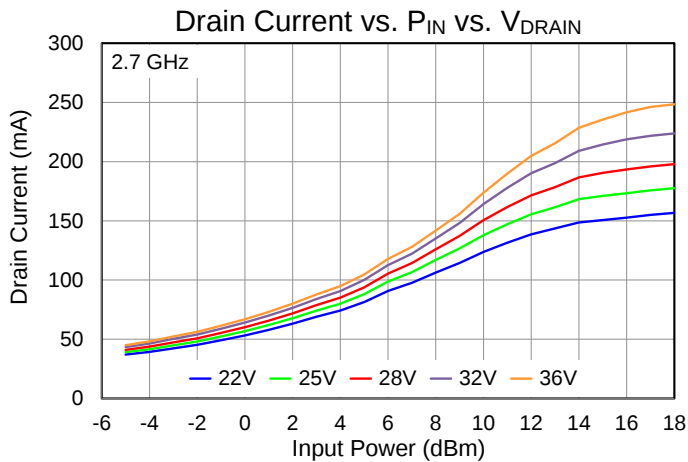
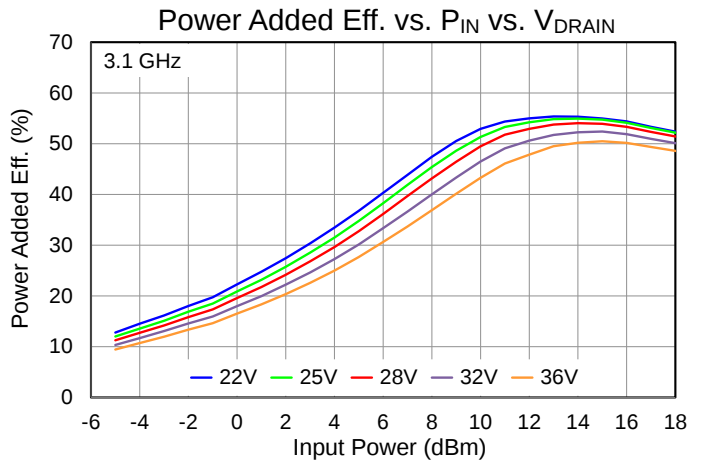
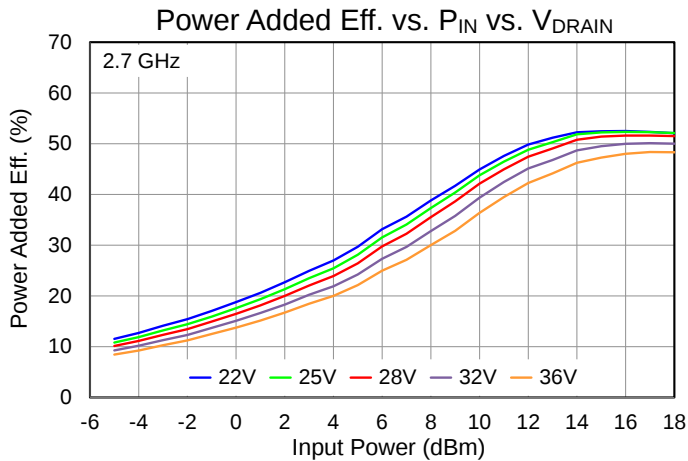
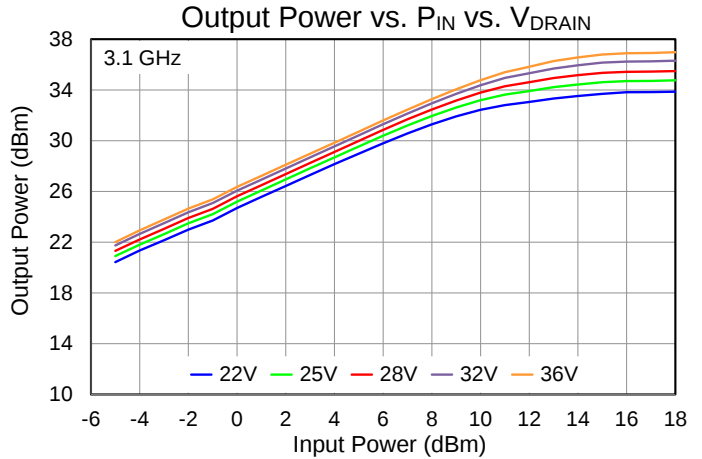
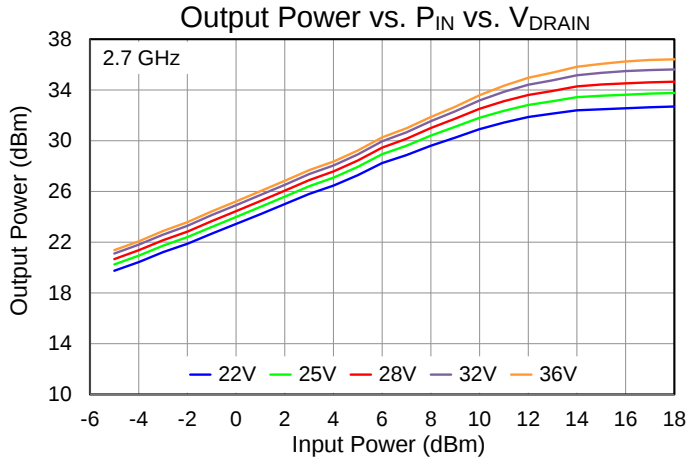
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25\text{ }^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



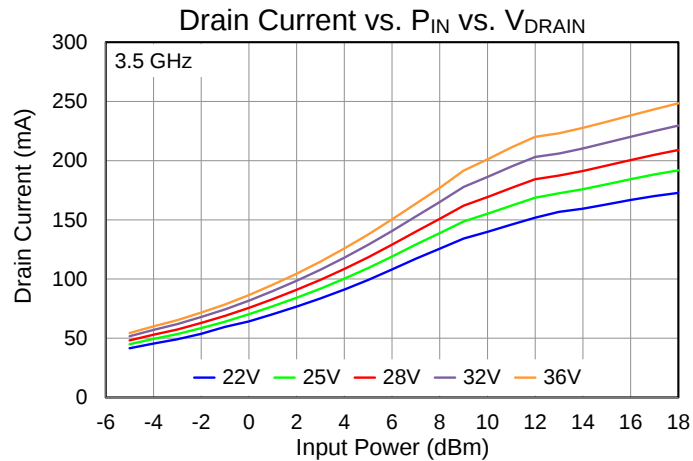
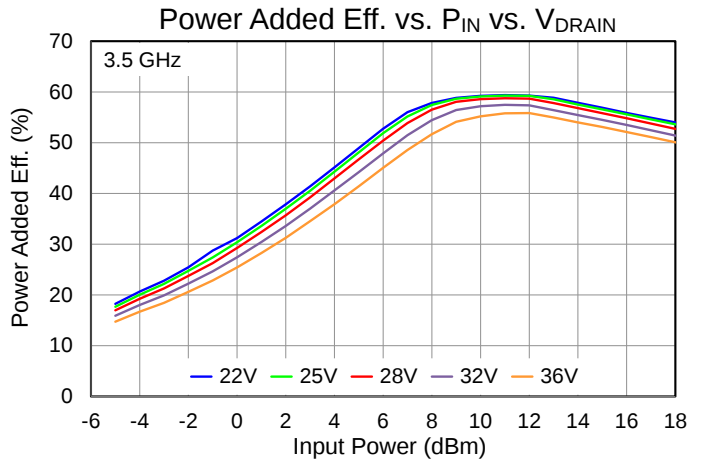
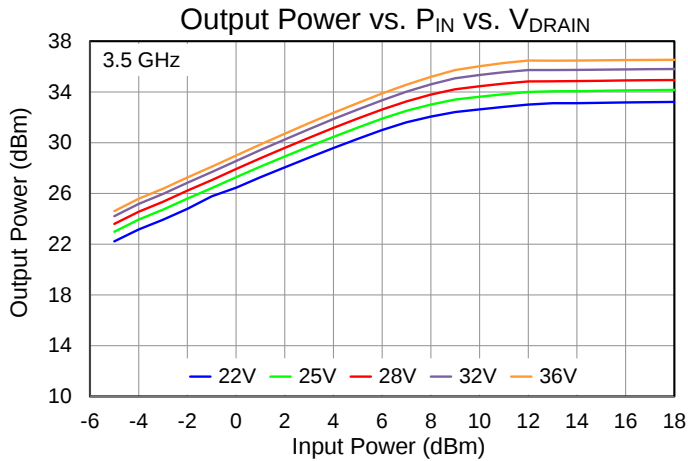
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25\text{ }^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



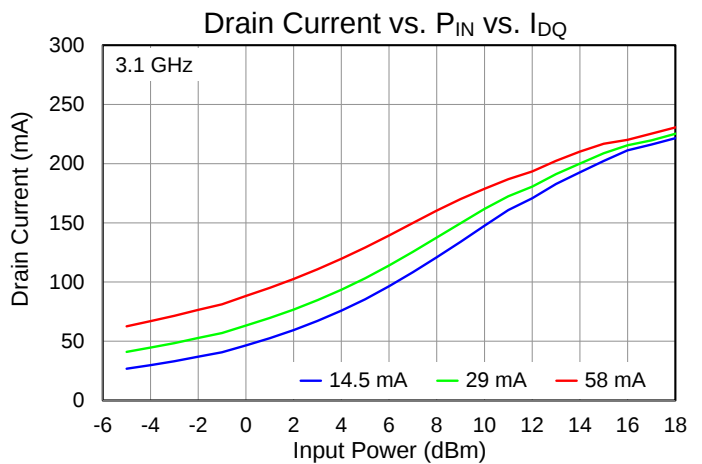
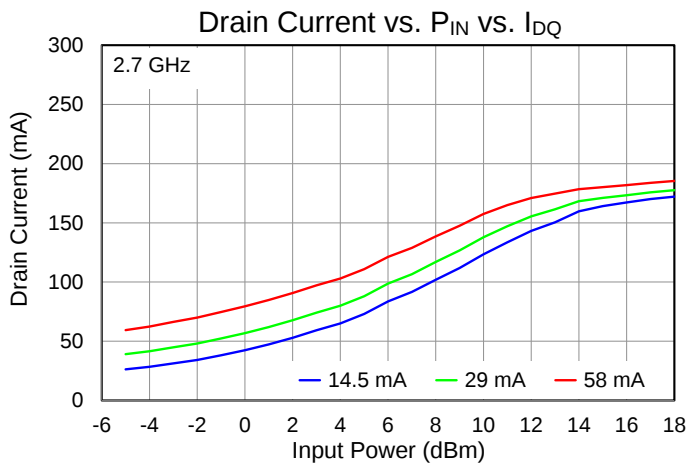
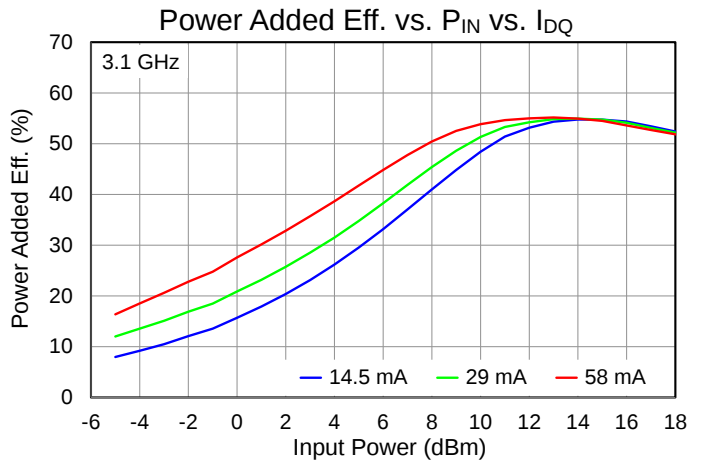
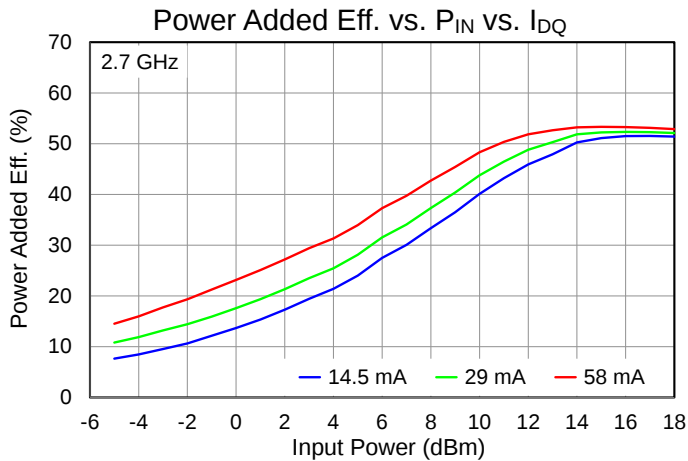
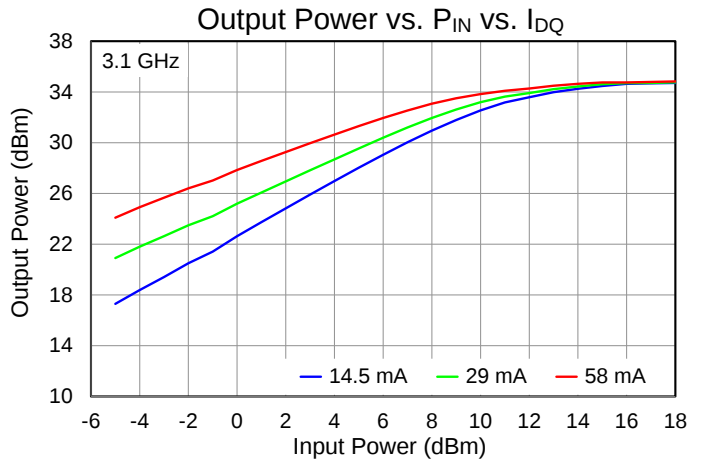
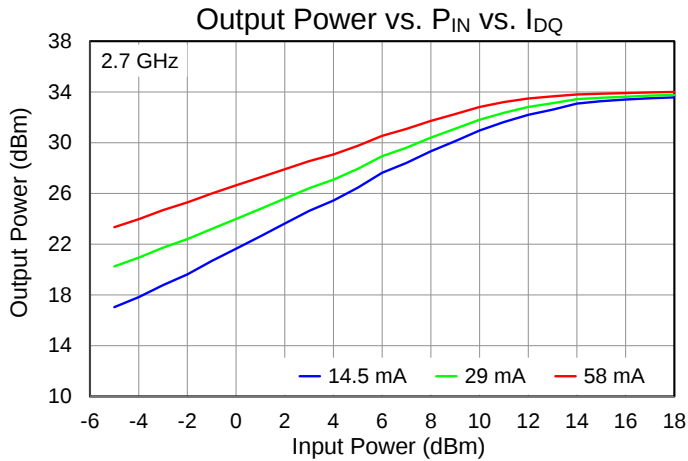
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25\text{ }^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



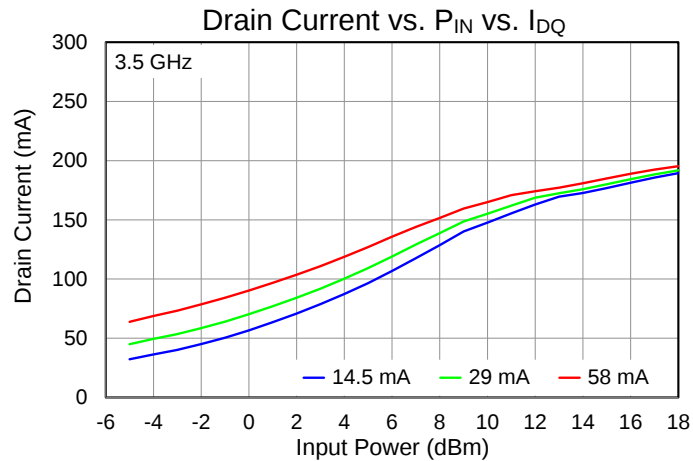
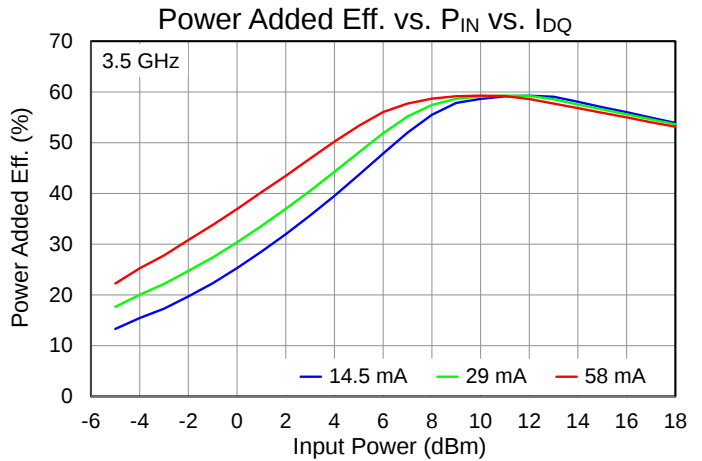
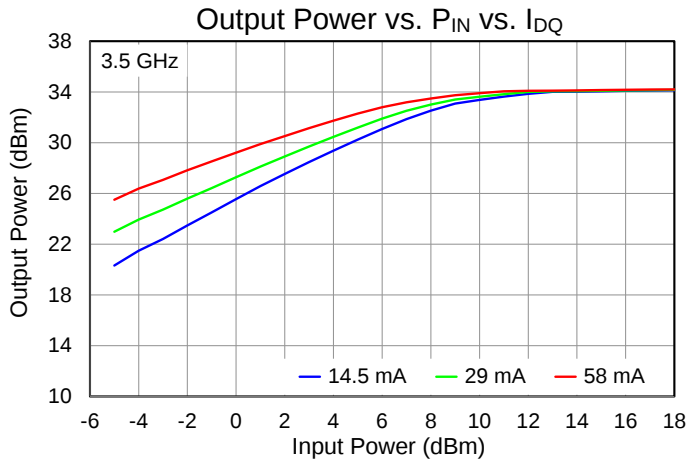
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25\text{ }^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



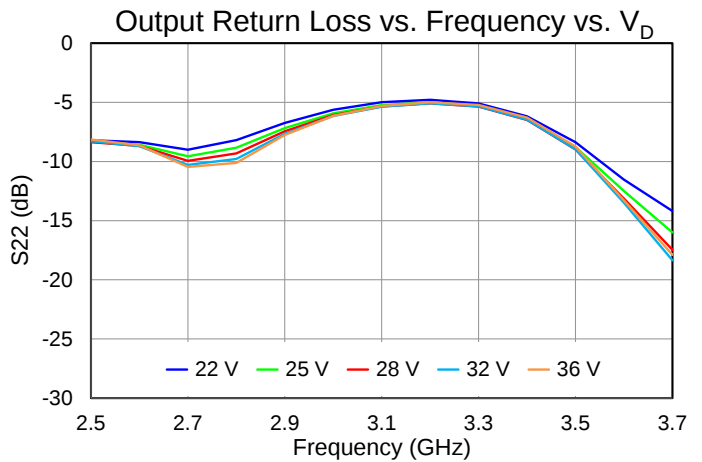
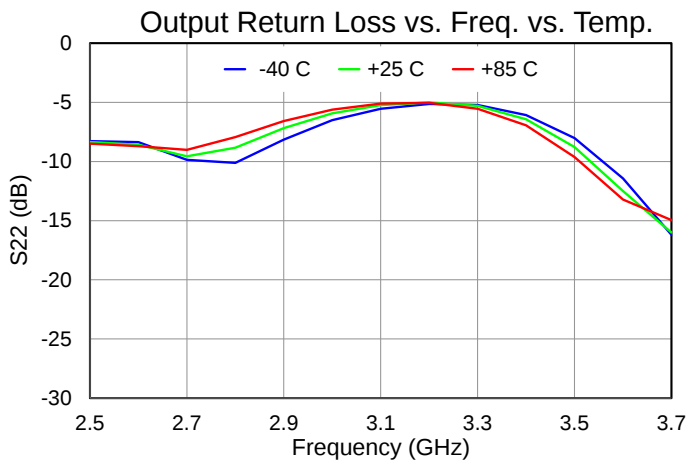
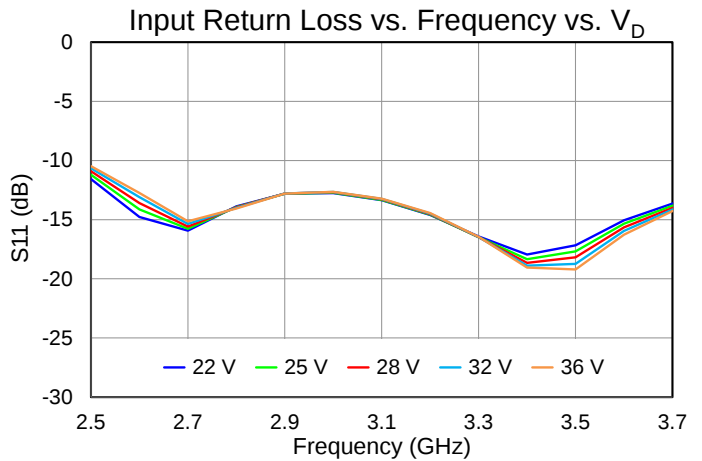
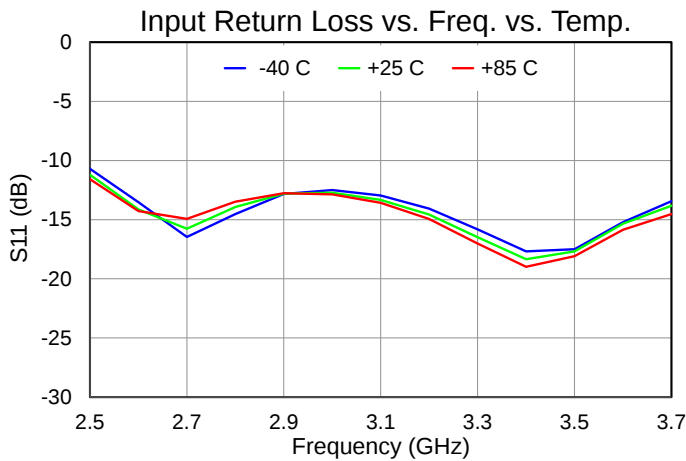
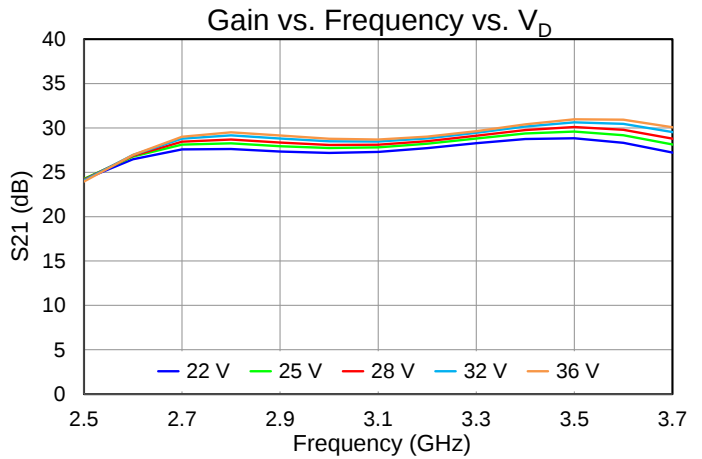
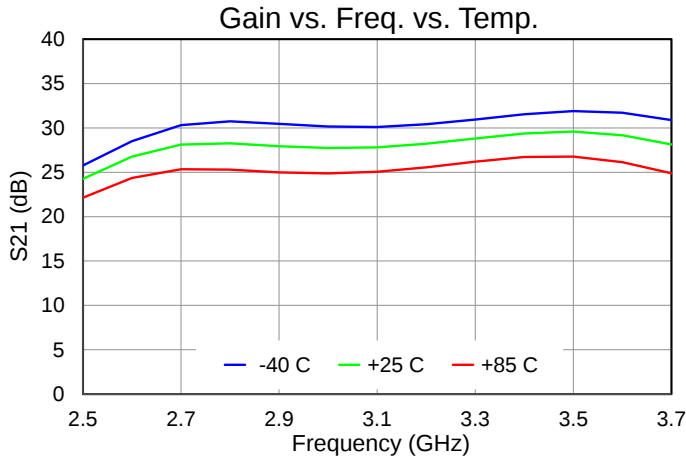
## Performance Plots – Large Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25\text{ }^\circ\text{C}$ ,  $P_{IN} = 15\text{ dBm}$ , CW



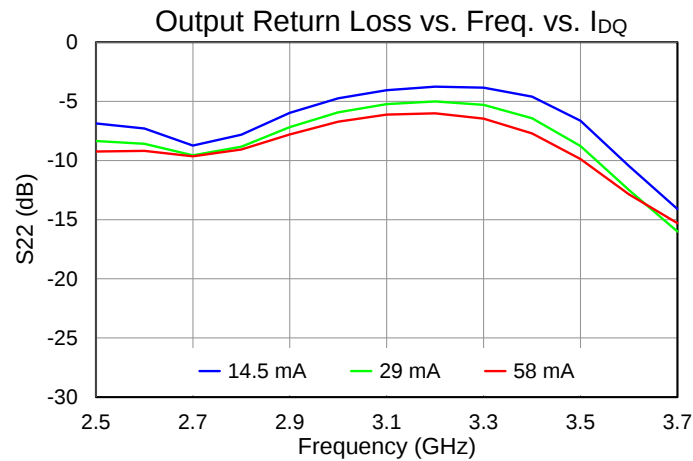
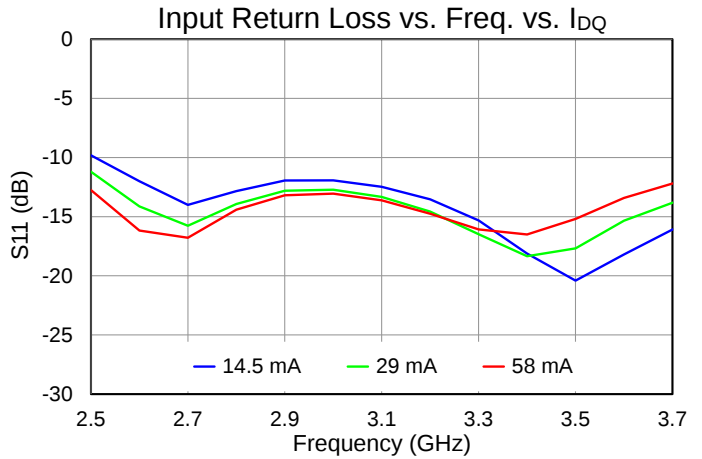
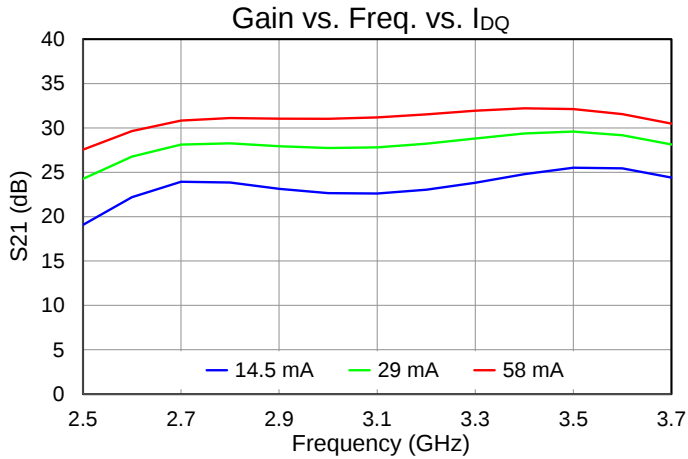
## Performance Plots – Small Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ , CW



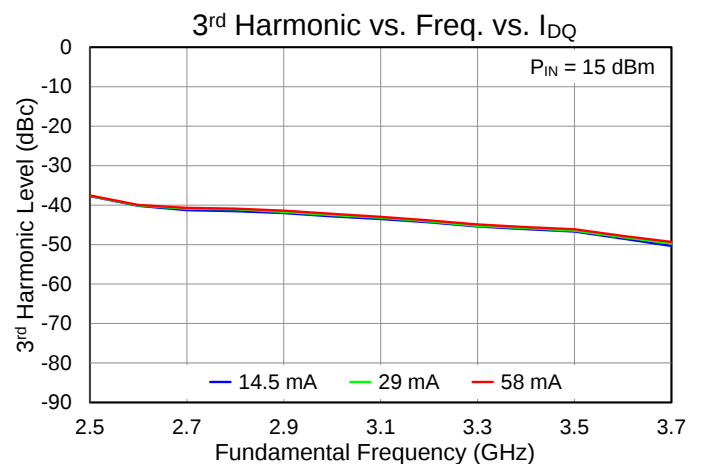
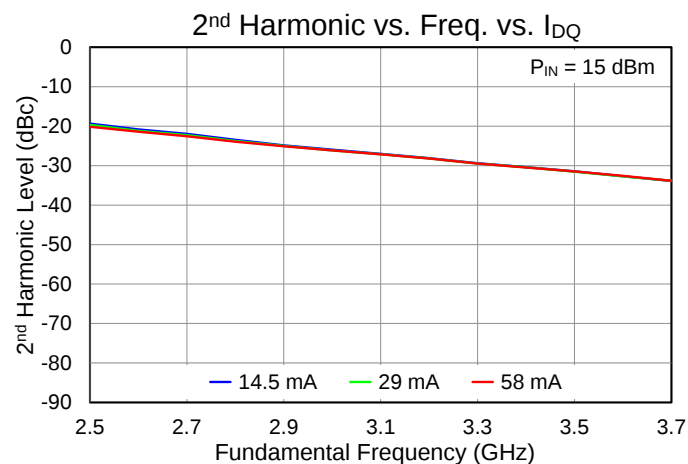
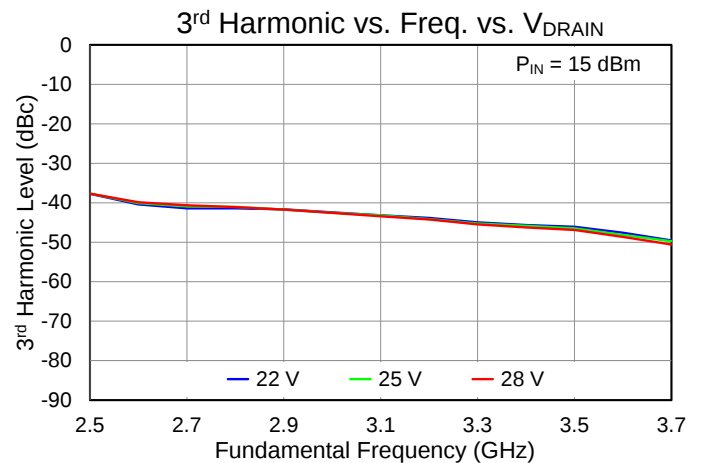
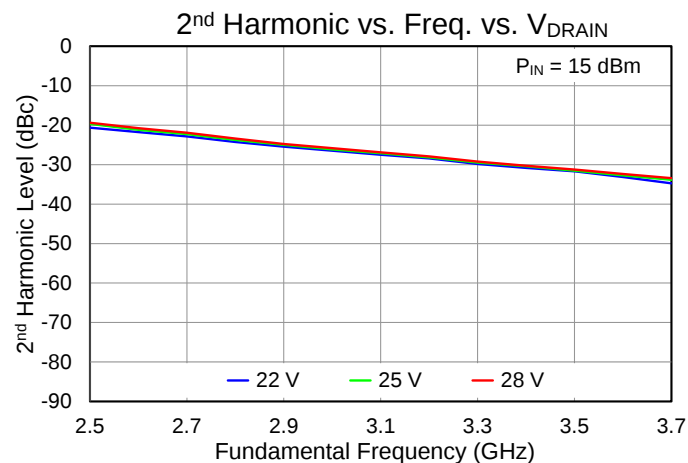
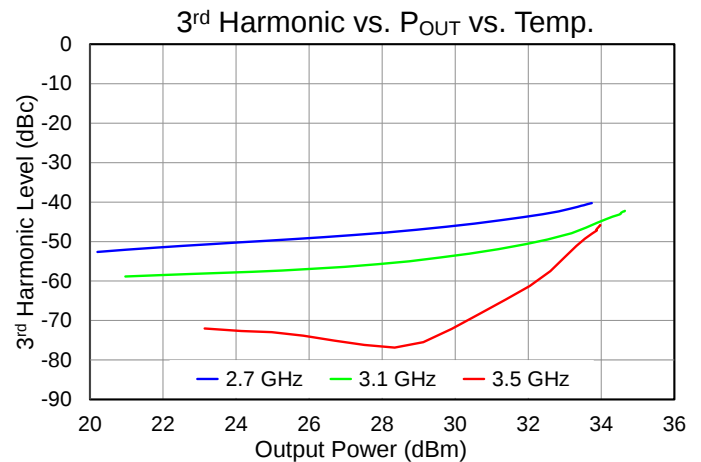
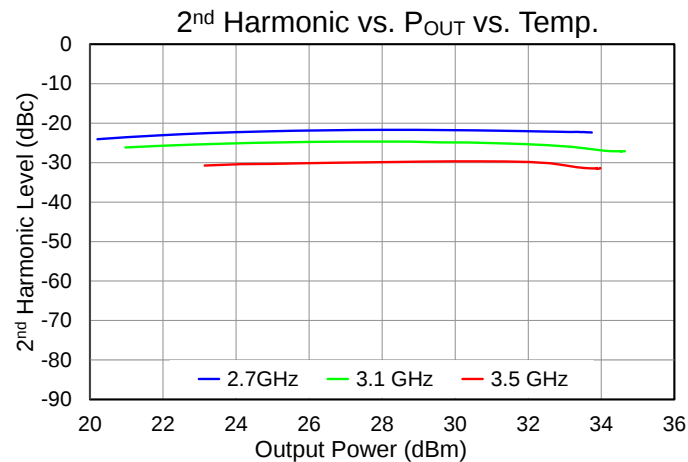
## Performance Plots – Small Signal

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ , CW



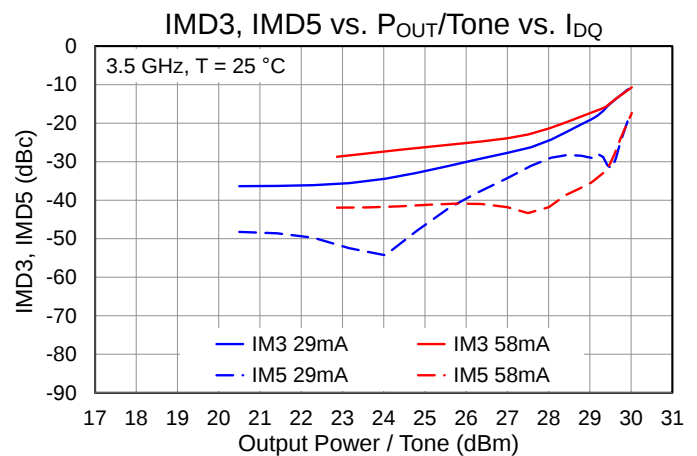
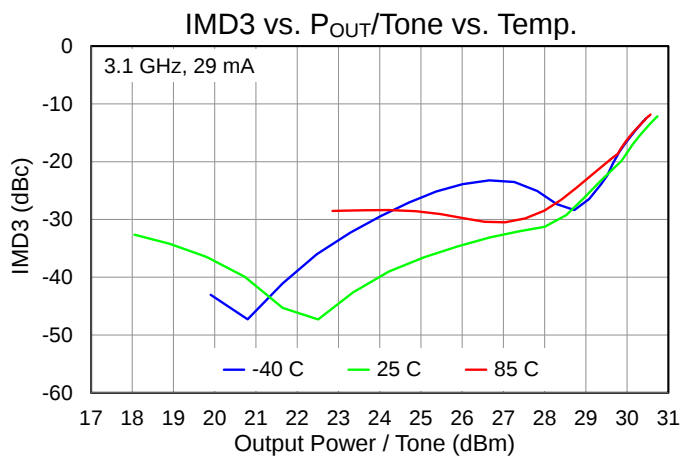
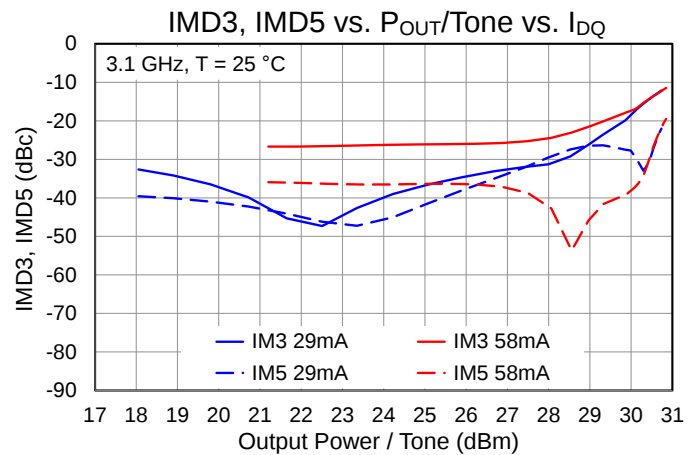
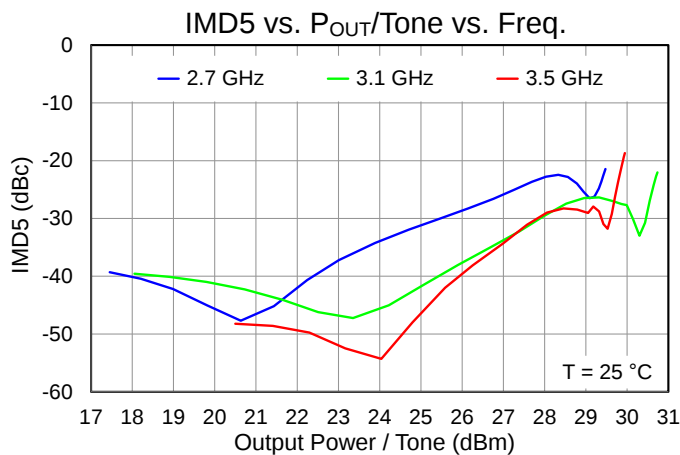
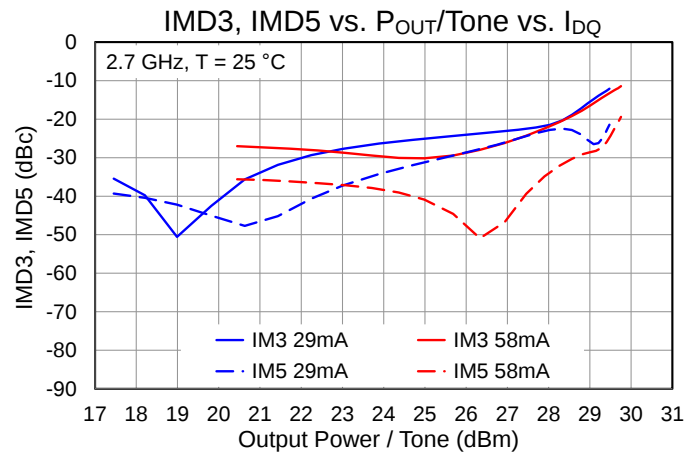
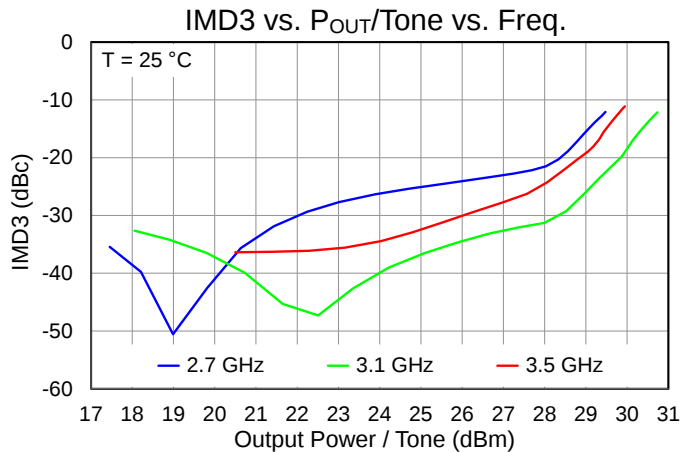
## Performance Plots – Harmonics

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ , CW



## Performance Plots – Linearity

Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$ , CW, Tone Spacing = 10 MHz



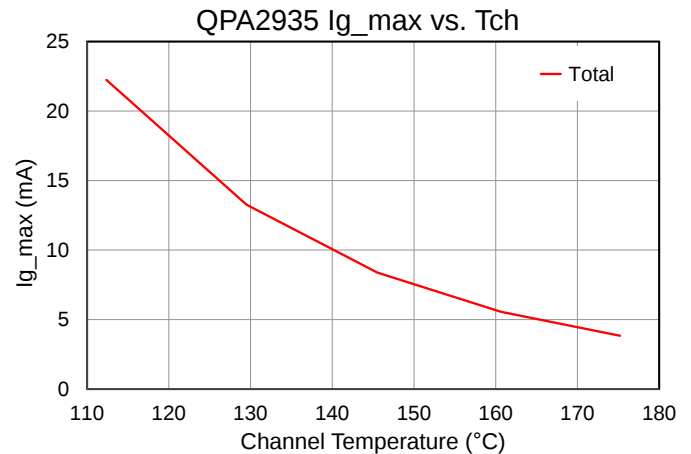
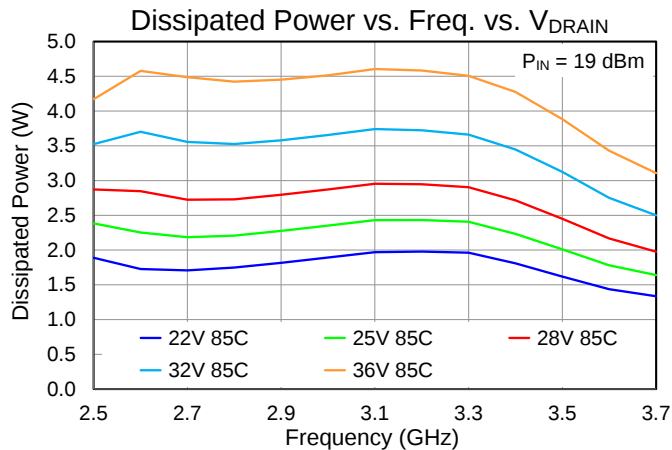
## Thermal and Reliability Information

| Parameter                                                  | Test Conditions                                                                                                                                                                                                            | Value | Units              |
|------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|--------------------|
| Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>        | $T_{base} = 85^\circ\text{C}$ , $V_D = 25\text{ V}$ , $I_{DQ} = 29\text{ mA}$ , $P_{DISS} = 0.725\text{ W}$<br>(Quiescent; no RF drive)                                                                                    | 8.936 | $^\circ\text{C/W}$ |
| Channel Temperature, $T_{CH}$ (Quiescent) <sup>(2)</sup>   |                                                                                                                                                                                                                            | 91.5  | $^\circ\text{C}$   |
| Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>        | $T_{base} = 85^\circ\text{C}$ , $V_D = 25\text{ V}$ , $I_{DQ} = 29\text{ mA}$ , Freq = 3.1 GHz,<br>$I_{D\_Drive} = 204\text{ mA}$ , $P_{IN} = 15\text{ dBm}$ , $P_{OUT} = 34.3\text{ dBm}$ ,<br>$P_{DISS} = 2.43\text{ W}$ | 9.189 | $^\circ\text{C/W}$ |
| Channel Temperature, $T_{CH}$ (w/ RF drive) <sup>(2)</sup> |                                                                                                                                                                                                                            | 107.3 | $^\circ\text{C}$   |

### Notes:

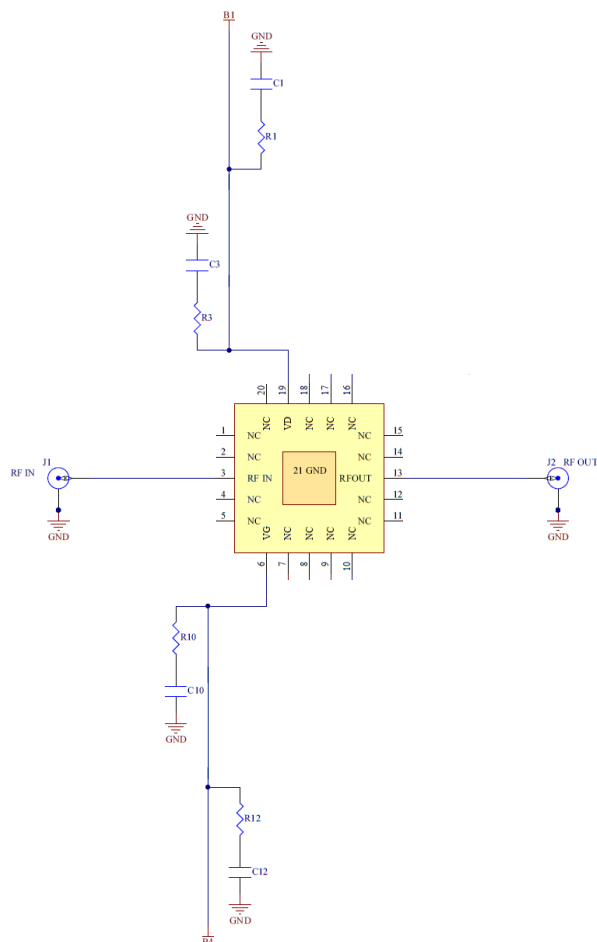
- Thermal resistance determined to the back of package,  $T_{base}$  ( $85^\circ\text{C}$ )
- $T_{CH}$  values are IR Scan equivalent temperatures. Refer to the following document: [GaN Device Channel Temperature, Thermal Resistance, and Reliability Estimates](#)

## Dissipated Power and Maximum Gate Current



Test conditions, unless otherwise noted:  $V_D = 25\text{ V}$ ,  $I_{DQ} = 29\text{ mA}$ ,  $T = +25^\circ\text{C}$

## Applications Information



### Bias-Up Procedure

Set  $V_D$  supply limit to 300 mA,  $V_G$  limit to 30 mA

Turn on  $V_G$  supply and set  $V_G = -4$  V

Turn on  $V_D$  supply and set  $V_D = 0$  V

Adjust  $V_D$  to 25 V

Adjust  $V_G$  to obtain desired  $I_{DQ}$  and apply RF

### Bias-Down Procedure

Turn off RF source

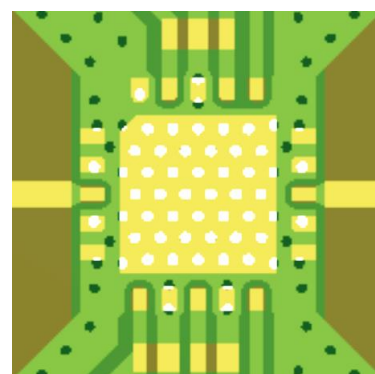
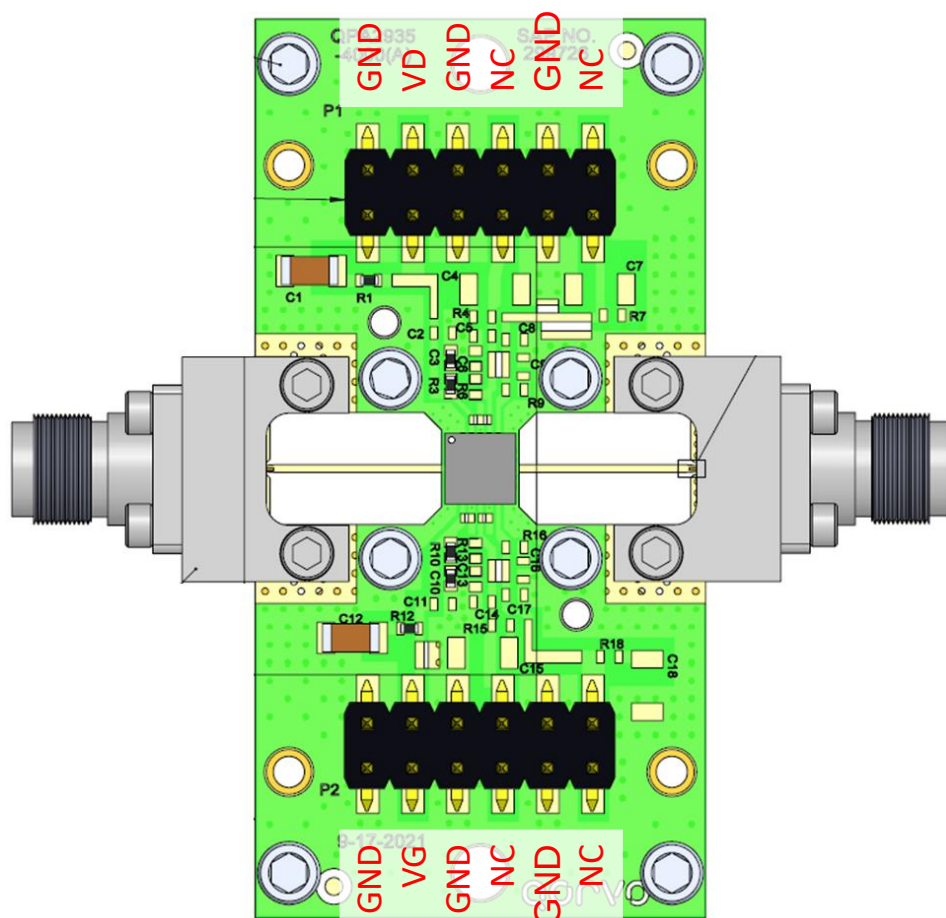
Set  $V_G = -4$  V

Set  $V_D = 0$  V

Turn off  $V_D$  Supply

Turn off  $V_G$  Supply

## Evaluation Board (EVB) Layout Assembly



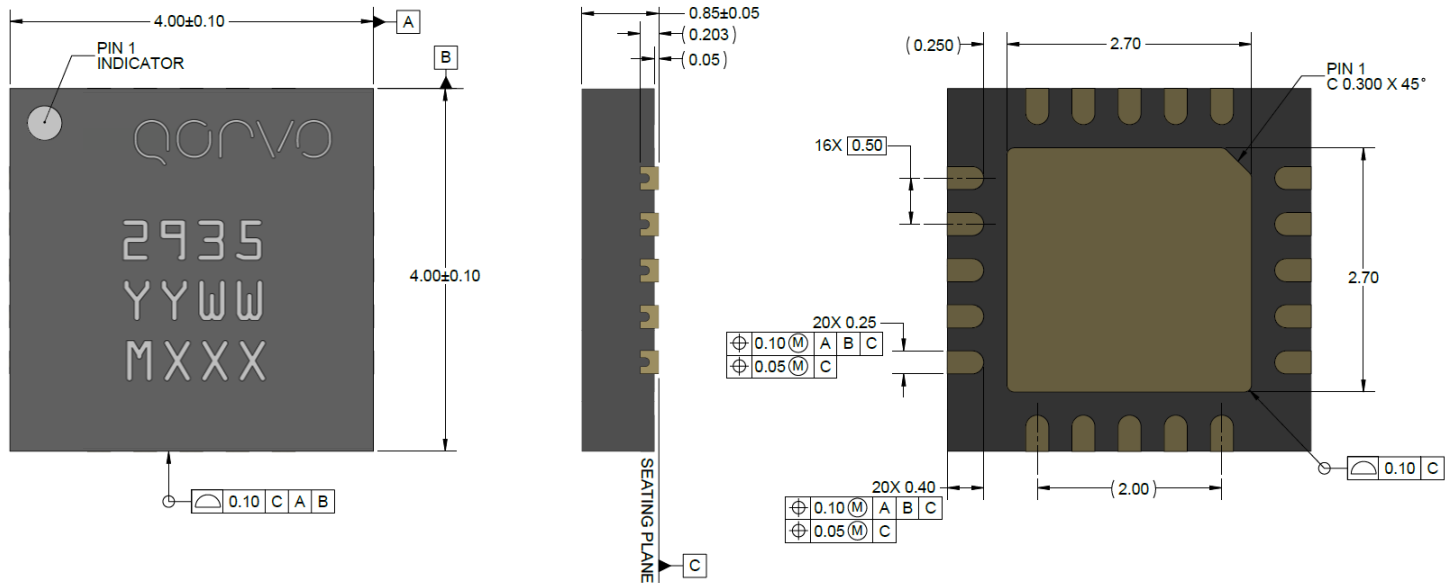
Package Mounting Detail

Thermal vias under the DUT are copper filled and over-plated for improved thermal management.  
Copper layers are 0.5 oz. both sides. PCB material is Rogers Corp. R4003C, .008 in. thick

## Bill of Materials

| Reference Des.   | Value   | Description                                | Manuf.              | Part No.   |
|------------------|---------|--------------------------------------------|---------------------|------------|
| C1, C12          | 1.0 uF  | CAP, 1uF, 5% 50V, X7R, 1206                | Various             |            |
| C3, C10          | 1000 pF | CAP, 1000pF, 10%, 100V, X7R, 0402          | Various             |            |
| R1, R3, R10, R12 | 10 Ohm  | RES, 10 OHM, 5%, 0.1W, 0402                | Various             |            |
| J1, J2           | 2.92 mm | CONN, 2.92, END, F, PIN .005, DIELECT .029 | Southwest Microwave | 1092-01A-5 |

## Mechanical Information



### Notes:

#### Material:

1. Package: plastic overmold compound
2. All package leads are gold plated

### Tolerances:

- .XX =  $\pm .25$
- .XXX =  $\pm .100$
- .XXXX =  $\pm .0245$

Unless otherwise specified, dimensions are in mm.

## Bond Pad Description

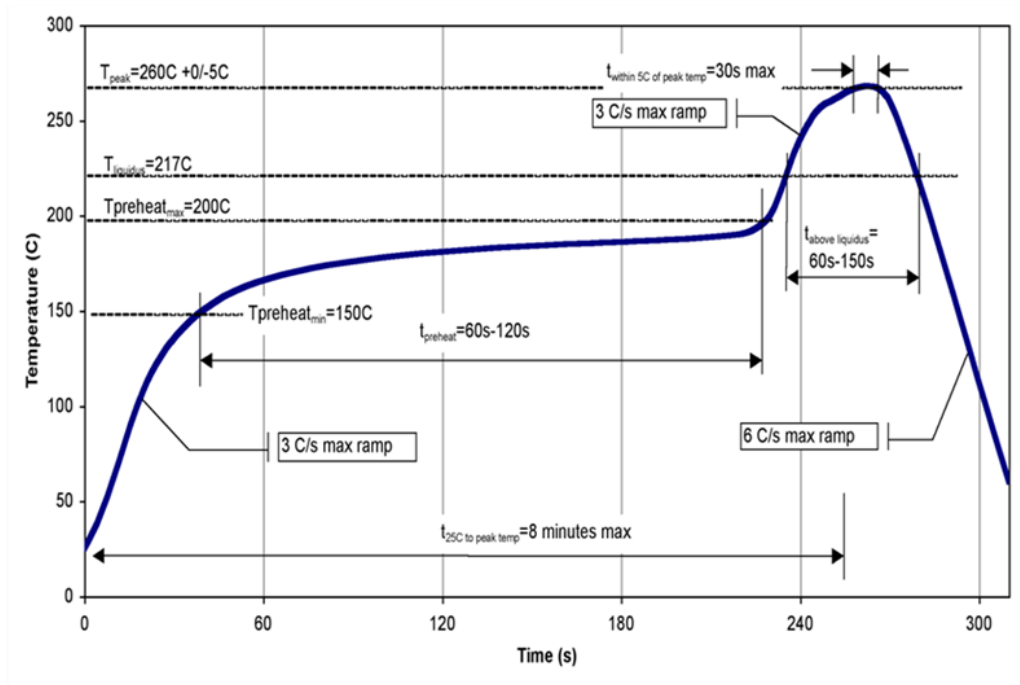
| Pad No.                     | Symbol | Description                                                                  |
|-----------------------------|--------|------------------------------------------------------------------------------|
| 1, 2, 4, 5, 7-12, 14-18, 20 | NC/GND | No internal connection. May be connected to PCB ground.                      |
| 3                           | RF IN  | RF input. 50 ohms. DC blocked.                                               |
| 6                           | VG     | Gate voltage. Bypassing required. See Applications Information for details.  |
| 13                          | RF OUT | RF output. 50 Ohms. DC blocked.                                              |
| 19                          | VD     | Drain voltage. Bypassing required. See Applications Information for details. |
| 21                          | GND    | Grounded center pad.                                                         |

## Assembly Notes

Compatible with lead-free soldering processes with 260°C peak reflow temperature.

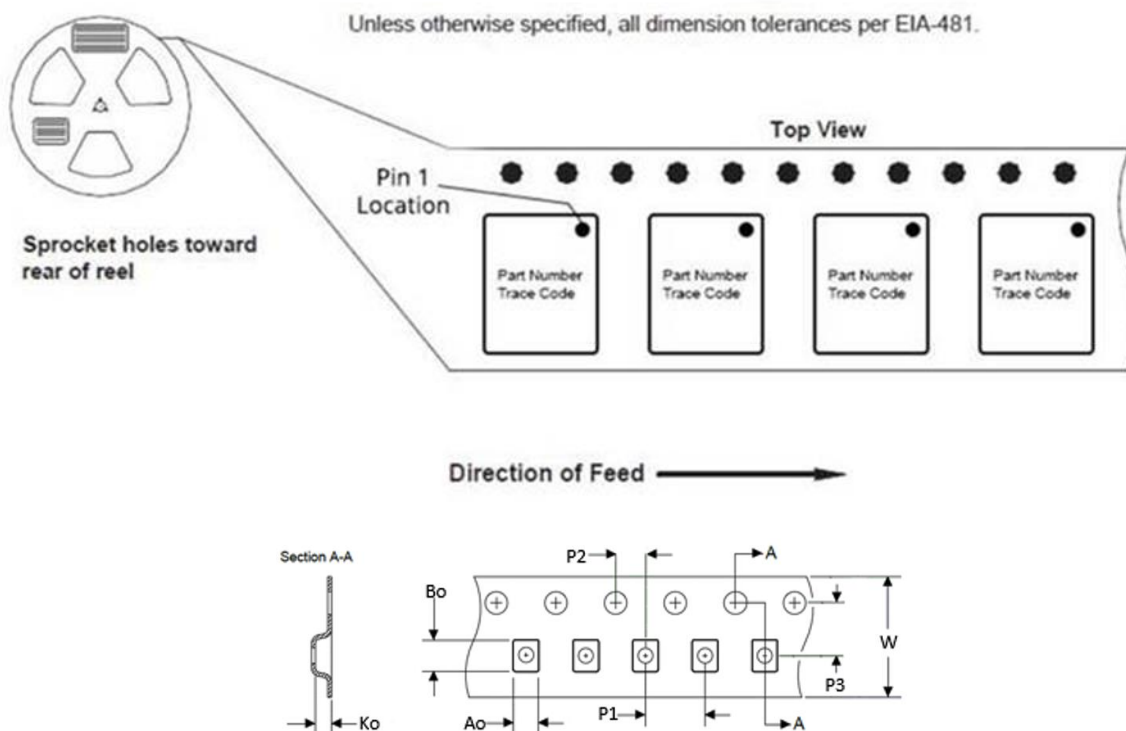
All package leads are gold plated

Solder rework is not recommended



## Tape and Reel Information – Carrier and Cover Tape Dimensions

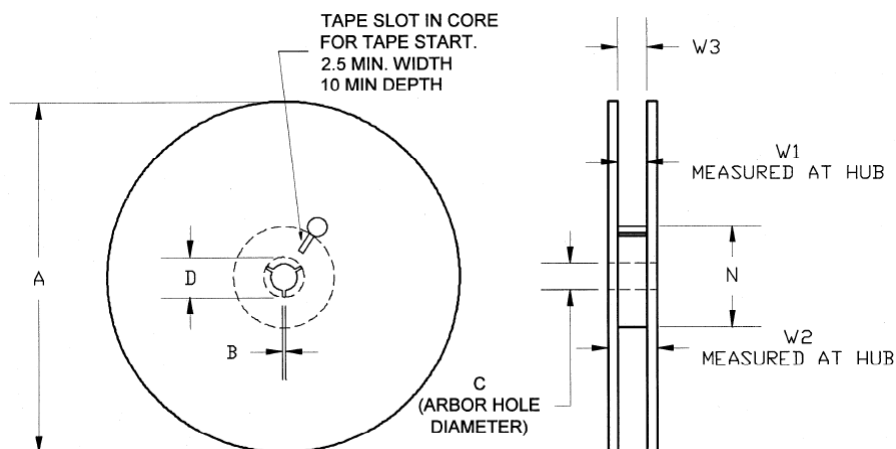
Tape and reel specifications for this part are also available on the Qorvo website.  
 Standard T/R size = 500 pieces on a 7" reel.



| Feature             | Measure                                  | Symbol | Size (in) | Size (mm) |
|---------------------|------------------------------------------|--------|-----------|-----------|
| Cavity              | Length                                   | A0     | 0.169     | 4.30      |
|                     | Width                                    | B0     | 0.169     | 4.30      |
|                     | Depth                                    | K0     | 0.049     | 1.25      |
|                     | Pitch                                    | P1     | 0.315     | 8.00      |
| Centerline Distance | Cavity to Perforation - Length Direction | P2     | 0.079     | 2.00      |
|                     | Cavity to Perforation - Width Direction  | F      | 0.217     | 5.50      |
| Cover Tape          | Width                                    | C      | 0.362     | 9.20      |
| Carrier Tape        | Width                                    | W      | 0.472     | 12.00     |

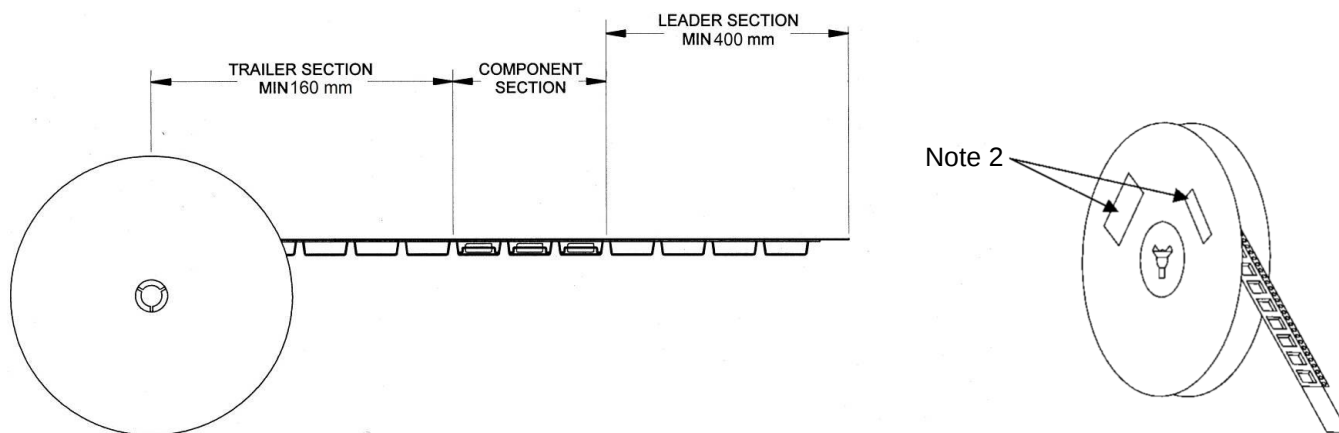
## Tape and Reel Information – Reel Dimensions

Packaging reels are used to prevent damage to devices during shipping and storage, loaded carrier tape is typically wound onto a plastic take-up reel. The reel size is 7" diameter. The reels are made from high-impact injection-molded polystyrene (HIPS), which offers mechanical and ESD protection to packaged devices.



| Feature | Measure              | Symbol | Size (in) | Size (mm) |
|---------|----------------------|--------|-----------|-----------|
| Flange  | Diameter             | A      | 6.969     | 177.0     |
|         | Thickness            | W2     | 0.724     | 18.4      |
|         | Space Between Flange | W1     | 0.488     | 12.4      |
| Hub     | Outer Diameter       | N      | 2.283     | 58.0      |
|         | Arbor Hole Diameter  | C      | 0.512     | 13.0      |
|         | Key Slit Width       | B      | 0.079     | 2.0       |
|         | Key Slit Diameter    | D      | 0.795     | 20.2      |

## Tape and Reel Information – Tape Length and Label Placement



### Notes:

1. Empty part cavities at the trailing and leading ends are sealed with cover tape. See EIA 481.
2. Labels are placed on the flange opposite the sprockets in the carrier tape.

## Handling Precautions

| Parameter                        | Rating | Standard                           |
|----------------------------------|--------|------------------------------------|
| ESD – Human Body Model (HBM)     | 1A     | ESDA / JEDEC JS-001-2017           |
| ESD – Charge Device Model (CDM)  | C3     | ESDA / JEDEC JS-002-2018           |
| MSL – Moisture Sensitivity Level | 3      | JEDEC standard IPC/JEDEC J-STD-020 |



Caution!

ESD-Sensitive Device

## RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU. This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C15H12Br4O2) Free
- PFOS Free
- SVHC Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

**Tel:** 1-844-890-8163

**Web:** [www.qorvo.com](http://www.qorvo.com)

**Email:** [customer.support@qorvo.com](mailto:customer.support@qorvo.com)

## Important Notice

The information contained herein is believed to be reliable; however, Qorvo makes no warranties regarding the information contained herein and assumes no responsibility or liability whatsoever for the use of the information contained herein. All information contained herein is subject to change without notice. Customers should obtain and verify the latest relevant information before placing orders for Qorvo products. The information contained herein or any use of such information does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other intellectual property rights, whether with regard to such information itself or anything described by such information. **THIS INFORMATION DOES NOT CONSTITUTE A WARRANTY WITH RESPECT TO THE PRODUCTS DESCRIBED HEREIN, AND QORVO HEREBY DISCLAIMS ANY AND ALL WARRANTIES WITH RESPECT TO SUCH PRODUCTS WHETHER EXPRESS OR IMPLIED BY LAW, COURSE OF DEALING, COURSE OF PERFORMANCE, USAGE OF TRADE OR OTHERWISE, INCLUDING THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE.**

Without limiting the generality of the foregoing, Qorvo products are not warranted or authorized for use as critical components in medical, life-saving, or life-sustaining applications, or other applications where a failure would reasonably be expected to cause severe personal injury or death.

© 2022 Qorvo US, Inc. All rights reserved. This document is subject to copyright laws in various jurisdictions worldwide and may not be reproduced or distributed, in whole or in part, without the express written consent of Qorvo US, Inc.

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Qorvo:](#)

[QPA2935](#) [QPA2935EVB](#) [QPA2935TR7](#)